

#### **PROTECTION PRODUCTS**

### Description

µClamp® TVS diodes are designed to protect sensitive electronics from damage or latch-up due to EOS, lightning, CDE, and ESD. They feature large crosssectional area junctions for conducting high transient currents. These devices offer desirable characteristics for board level protection including fast response time, low operating and clamping voltage, and no device degradation.

The µClamp<sup>®</sup>xx71P series are in 2-pin SGP1610N2 package measuring 1.6 x 1.0 mm with a nominal height of 0.57mm. The leads are finished with leadfree NiPdAu. They may be used to protect 5V, 8V, 10V, 12V, 15V, 18V, 22V, 26V, and 36V systems. They feature high surge current capability and low clamping voltage making them ideal for use in harsh transient environments.

#### Features

- Transient protection for high-speed data lines to
- IEC 61000-4-2 (ESD) 30kV (air), 30kV (contact)
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 20 80A (8/20μs)
- Protects one data or power line
- Low leakage current
- High peak pulse current capability
- Operating voltage options: 5V, 8V, 10V, 12V, 15V,
- 18V, 22V, 26V, 36V
- Solid-state silicon-avalanche technology

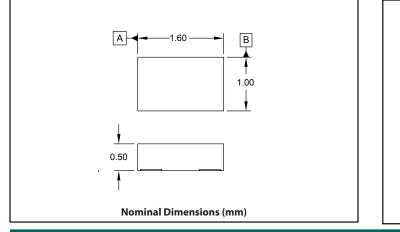
#### **Mechanical Characteristics**

- SGP1610N2 package
- Pb-Free, Halogen Free, RoHS/WEEE Compliant
- Nominal Dimensions: 1.6 x 1.0 x 0.57 mm
- Lead Finish: NiPdAu
- Marking: Marking code
- Packaging: Tape and Reel

### **Applications**

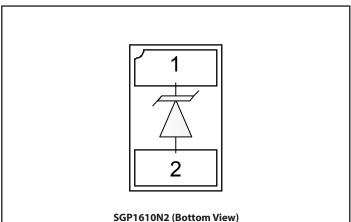
- Cellular Handsets & Accessories
- USB Voltage Bus
- Battery Protection
- Digital Lines
- Proximity Sensors

#### **Package Dimension**



#### μClamp0571P - μClamp3671P Final Datasheet Rev 8.0 Revision date 1/11/2018

### **Schematic & Pin Configuration**



## **Absolute Maximum Rating**

Rating	Symbol	Value	Units
Peak Pulse Power (tp = $8/20\mu s$ )	P <sub>PK</sub>	1200-1500	W
ESD per IEC 61000-4-2 (Air) <sup>1</sup> ESD per IEC 61000-4-2 (Contact) <sup>1</sup>	V <sub>ESD</sub>	±30 ±30	kV
Operating Temperature	T	-40 to +125	°C
Storage Temperature	T <sub>STG</sub>	-55 to +150	°C

## **Electrical Characteristics (T=25°C unless otherwise specified)**

μClamp0571P									
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Units		
Reverse Stand-Off Voltage	V <sub>RWM</sub>	Pin 1 to 2				5	V		
Reverse Breakdown Voltage	V <sub>BR</sub>	I <sub>BR</sub> = 1mA, Pin 1 to 2		6	7	9	V		
Reverse Leakage Current	I <sub>R</sub>	$V_{RWM} = 5V$	T = 25°C		<10	100	nA		
Peak Pulse Current	l pp	tp = 8/20µs, Pin 1 to 2				80	А		
		ha 0/20-s	$I_{PP} = 40A$			10			
Clamping Voltage	V <sub>c</sub>	$tp = 8/20\mu s$ $I_{pp} = 80A$		$tp = 8/20\mu s$ $I_{pp} = 80A$	I <sub>PP</sub> = 80A			15	V
Dynamic Resistance <sup>2,3</sup>	R <sub>DYN</sub>	tp = 0.2/100ns			0.05		Ω		
Junction Capacitance	C	$V_{R} = 0V, f = 1MHz$				675	pF		

μClamp0871P							
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Units
Reverse Stand-Off Voltage	V <sub>RWM</sub>	Pin 1 to 2				8	V
Reverse Breakdown Voltage	V <sub>BR</sub>	I <sub>BR</sub> = 1mA, Pin 1 to 2		9.5	11	13	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 8V	$V_{RWM} = 8V$ $T = 25^{\circ}C$		<10	100	nA
Peak Pulse Current	l <sub>pp</sub>	tp = 8/20µs, Pin 1 to 2				65	А
			$I_{pp} = 10A$			15	
Clamping Voltage	V <sub>c</sub>	tp = $8/20\mu s$ I <sub>pp</sub> = $65A$				23	V
Dynamic Resistance <sup>2,3</sup>	R <sub>DYN</sub>	tp = 0.2/100ns	1		0.05		Ω
Junction Capacitance	C	$V_{R} = 0V, f = 1MHz$				475	pF

# Electrical Characteristics (T=25°C unless otherwise specified)

#### µClamp1071P

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Units
Reverse Stand-Off Voltage	V <sub>RWM</sub>	Pin 1 to 2				10	V
Reverse Breakdown Voltage	V <sub>BR</sub>	I <sub>BR</sub> = 1mA, Pin 1 to 2		12	13.5	15.5	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 10V, Pin 1 to 2	T = 25°C		<10	100	nA
Peak Pulse Current	l <sub>pp</sub>	tp = 8/20µs , Pin 1 to 2				60	А
		ha 0/20 a	$I_{pp} = 10A$			17	
Clamping Voltage	V <sub>c</sub>	tp = 8/20µs	I <sub>PP</sub> = 60A			25	V
Dynamic Resistance <sup>2,3</sup>	R <sub>DYN</sub>	tp = 0.2/100ns			0.05		Ω
Junction Capacitance	C	$V_{R} = 0V, f = 1MHz$				350	pF

μClamp1271P							
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Units
Reverse Stand-Off Voltage	V <sub>RWM</sub>	Pin 1 to 2				12	V
Reverse Breakdown Voltage	V <sub>BR</sub>	I <sub>BR</sub> = 1mA, Pin 1 to 2		14	16	19	V
Reverse Leakage Current	I <sub>R</sub>	$V_{RWM} = 12V$ , Pin 1 to 2	T = 25°C		<10	100	nA
Peak Pulse Current	I pp	tp = 8/20µs , Pin 1 to 2	·			45	А
			$I_{PP} = 10A$			22	
Clamping Voltage	V <sub>c</sub>	tp = 8/20µs	$I_{PP} = 45A$			30	V
Dynamic Resistance <sup>2,3</sup>	R <sub>DYN</sub>	tp = 0.2/100ns			0.05		Ω
Junction Capacitance	C	$V_{R} = 0V, f = 1MHz$				275	pF

μClamp1571P							
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Units
Reverse Stand-Off Voltage	V <sub>RWM</sub>	Pin 1 to 2				15	V
Reverse Breakdown Voltage	V <sub>BR</sub>	I <sub>BR</sub> = 1mA, Pin 1 to 2		17.5	20	23	V
Reverse Leakage Current	I <sub>R</sub>	$V_{RWM} = 15V$ , Pin 1 to 2	T = 25°C		<10	100	nA
Peak Pulse Current	l <sub>pp</sub>	tp = 8/20µs , Pin 1 to 2				40	А
		tp = 8/20µs	I <sub>PP</sub> = 10A			25	
Clamping Voltage	V <sub>c</sub>	Pin 1 to 2	I <sub>PP</sub> = 40A			40	V
Dynamic Resistance <sup>2,3</sup>	R <sub>DYN</sub>	tp = 0.2/100ns			0.05		Ω
Junction Capacitance	C	$V_{R} = 0V, f = 1MHz$				220	pF

μClamp1871P							
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Units
Reverse Stand-Off Voltage	V <sub>RWM</sub>	Pin 1 to 2				18	V
Reverse Breakdown Voltage	V <sub>BR</sub>	I <sub>BR</sub> =1mA, Pin 1 to 2		20	22	25	V
Reverse Leakage Current	I <sub>R</sub>	$V_{RWM} = 18V$ , Pin1 to 2	T = 25°C		<10	100	nA
Peak Pulse Current	I pp	tp = 8/20µs , Pin 1 to 2				35	A
			$I_{PP} = 10A$			28	
Clamping Voltage	V <sub>c</sub>	tp = 8/20µs	$I_{PP} = 35A$			45	- V
Dynamic Resistance <sup>2,3</sup>	R <sub>DYN</sub>	tp = 0.2/100ns			0.10		Ω
Junction Capacitance	C	$V_{R} = 0V, f = 1MHz$				225	pF

μClamp2271P							
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Units
Reverse Stand-Off Voltage	V <sub>RWM</sub>	Pin 1 to 2				22	V
Reverse Breakdown Voltage	V <sub>BR</sub>	$I_{BR} = 1 \text{ mA}$ , Pin 1 to 2	I <sub>BR</sub> = 1mA, Pin 1 to 2		29	33.5	V
Reverse Leakage Current	I <sub>R</sub>	$V_{RWM} = 22V$ , Pin 1 to 2	T = 25°C		<10	100	nA
Peak Pulse Current	l pp	tp = 8/20µs , Pin 1 to 2				25	А
Channel and Valley and			$I_{PP} = 10A$			40	
Clamping Voltage	V <sub>c</sub>	tp = 8/20µs, Pin 1 to 2	I <sub>PP</sub> = 25A			55	V
Dynamic Resistance <sup>2,3</sup>	R <sub>DYN</sub>	tp = 0.2/100ns	÷		0.10		Ω
Junction Capacitance	C	$V_{R} = 0V, f = 1MHz$				165	pF

μClamp2671P							
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Units
Reverse Stand-Off Voltage	V <sub>RWM</sub>	Pin 1 to 2				26	V
Reverse Breakdown Voltage	V <sub>BR</sub>	I <sub>BR</sub> = 1mA, Pin 1 to 2		29	32	35	V
Reverse Leakage Current	I <sub>R</sub>	$V_{RWM} = 5V$	T = 25°C		<10	100	nA
Peak Pulse Current	I <sub>pp</sub>	tp = 8/20µs , Pir	n 1 to 2			23	А
			I <sub>PP</sub> = 10A			50	
Clamping Voltage	V <sub>c</sub>	tp = 8/20µs	I <sub>PP</sub> = 23A			65	V
Dynamic Resistance <sup>2,3</sup>	R <sub>DYN</sub>	tp = 0.2/100ns	<u>.</u>		0.15		Ω
Junction Capacitance	C	$V_{R} = 0V, f = 1MH$	lz			155	pF

μClamp3671P							
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Units
Reverse Stand-Off Voltage	V <sub>RWM</sub>	Pin 1 to 2				36	V
Reverse Breakdown Voltage	V <sub>BR</sub>	I <sub>BR</sub> = 1mA, Pin 1 to 2		37		44	V
Reverse Leakage Current	I <sub>R</sub>	$V_{RWM} = 36V$	T = 25°C		<10	100	nA
Peak Pulse Current	l <sub>pp</sub>	tp = 8/20µs , Pir	n 1 to 2			18	A
			$I_{pp} = 2A$			48	
Clamping Voltage	V <sub>c</sub>	tp = 8/20µs	I <sub>PP</sub> = 18A			80	- V
Dynamic Resistance <sup>2,3</sup>	R <sub>DYN</sub>	tp = 0.2/100ns	1		0.29		Ω
Junction Capacitance	C	$V_{R} = 0V, f = 1MH$	Iz			150	pF

Notes

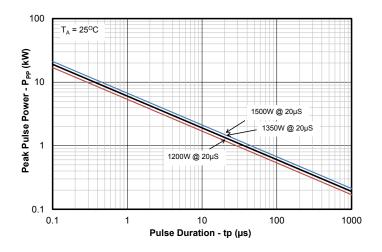
1) Measured with a 40dB attenuator, 50 Ohm scope input impedance, 2GHz bandwidth. ESD gun return path connected to ESD ground plane.

2) Transmission Line Pulse Test (TLP) Settings: tp = 100ns, tr = 0.2ns,  $I_{TLP}$  and  $V_{TLP}$  averaging window: t1 = 70ns to t2 = 90ns.

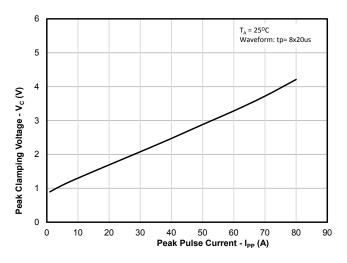
3) Dynamic resistance calculated from  $\rm I_{\rm TLP}$  = 4A to  $\rm I_{\rm TLP}$  = 16A

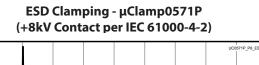
## **Typical Characteristics**

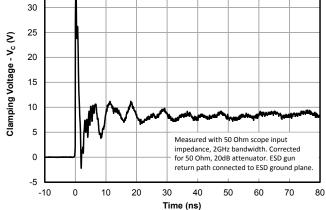
Non-Repetitive Peak Pulse Power vs. Pulse Time



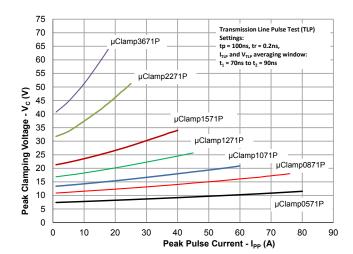
Forward Voltage vs. Peak Pulse Current (tp =  $8/20 \ \mu s$ )



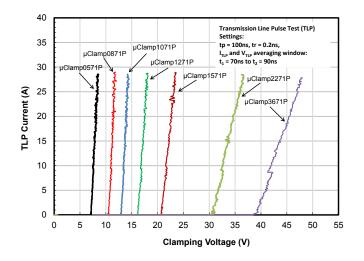




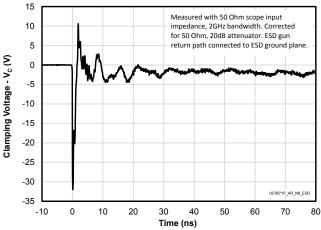
Clamping Voltage vs. Peak Pulse Current (tp = 8/20 µs)







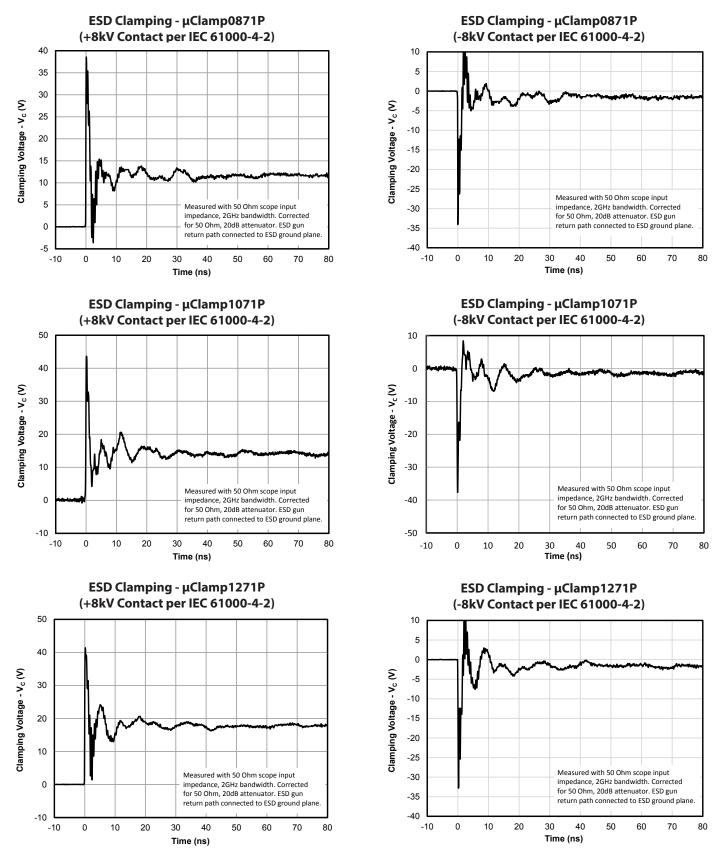
ESD Clamping - μClamp0571P (-8kV Contact per IEC 61000-4-2)



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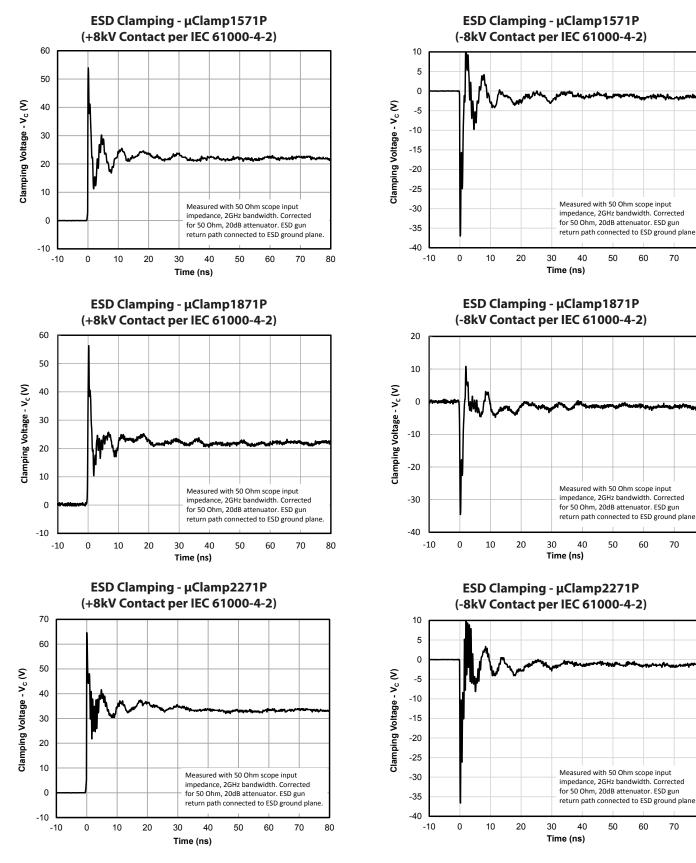
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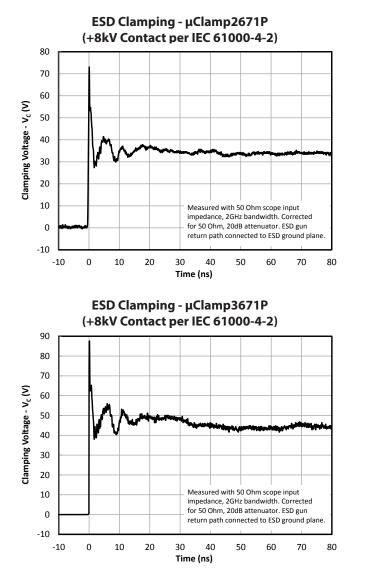
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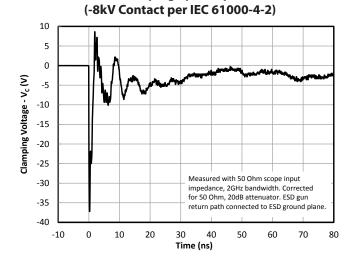
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ESD Clamping - µClamp2671P (-8kV Contact per IEC 61000-4-2) 10 5 0 Clamping Voltage - V<sub>c</sub> (V) -5 -10 -15 -20 -25 Measured with 50 Ohm scope input -30 impedance, 2GHz bandwidth. Corrected for 50 Ohm, 20dB attenuator. ESD gun -35 return path connected to ESD ground plane -40 0 -10 10 20 30 40 50 60 70 80 Time (ns) ESD Clamping - µClamp3671P

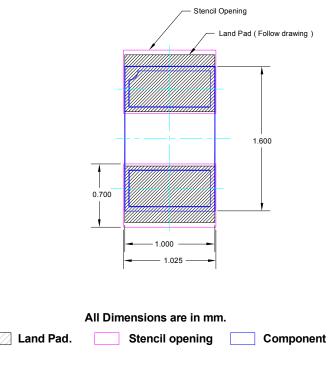


## **Application Information**

#### **Assembly Guidelines**

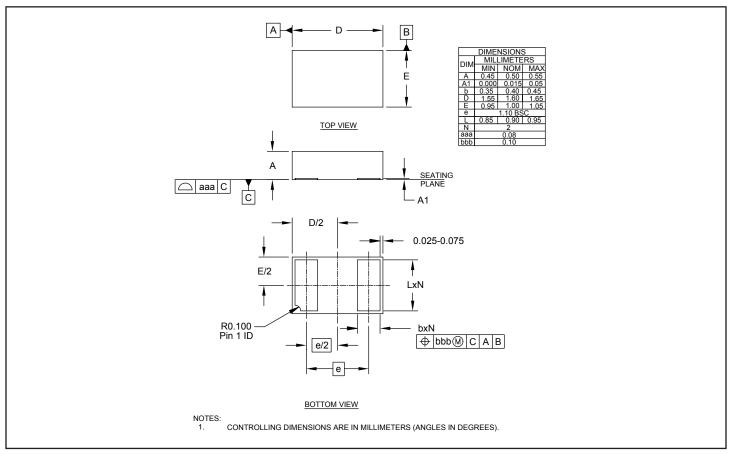
The table below provides Semtech's recommended assembly guidelines for mounting this device. The figure at the right details Semtech's recommended aperture based on the below recommendations. Note that these are only recommendations and should serve only as a starting point for design since there are many factors that affect the assembly process. The exact manufacturing parameters will require some experimentation to get the desired solder application.

Assembly Parameter	Recommendation
Solder Stencil Design	Laser cut, Electro-polished
Aperture shape	Rectangular with rounded
	corners
Solder Stencil Thickness	0.125 mm (0.005")
Solder Paste Type	Type 3 size sphere or smaller
Solder Reflow Profile	per JEDEC J-STD-020
PCB Solder Pad Design	Non-Solder mask defined
PCB Pad Finish	OSP OR NiAu

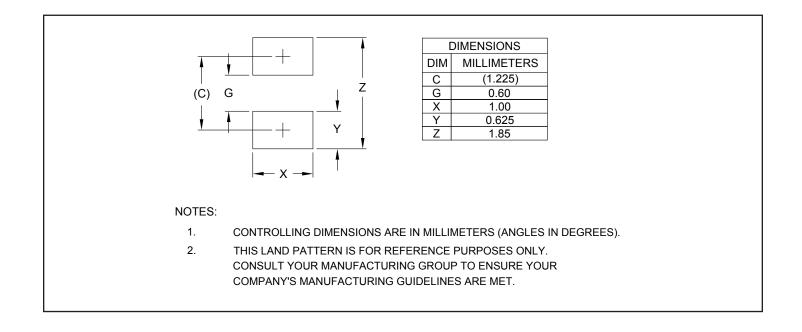


#### **Recommended Mounting Pattern**

## **Outline Drawing - SGP1610N2**



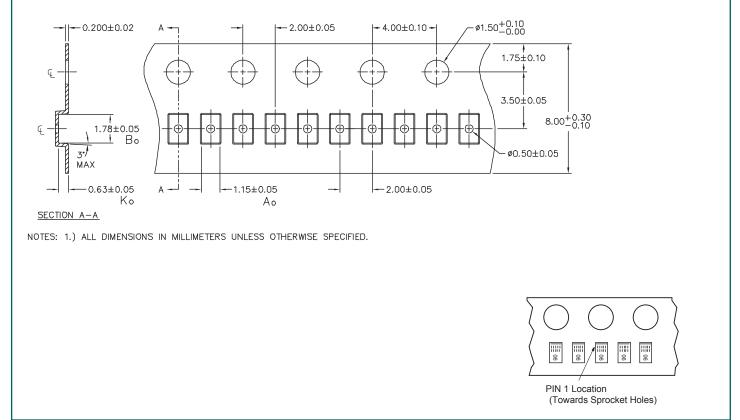
## Land Pattern - SGP1610N2



## **Marking Code**

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## **Tape and Reel Specification**



### **Ordering Information**

<u> </u>			
Part Number	Marking Code	Working Voltage	Qty per Reel
µClamp0571P.TNT	06	5V	10,000
µClamp0871P.TNT	11	8V	10,000
µClamp1071P.TNT	12	10V	10,000
µClamp1271P.TNT	16	12V	10,000
µClamp1571P.TNT	18	15V	10,000
µClamp1871P.TNT	24	18V	10,000
µClamp2271P.TNT	26	22V	10,000
µClamp2671P.TNT	30	26V	10,000
µClamp3671P.TNT	37	36V	10,000



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